

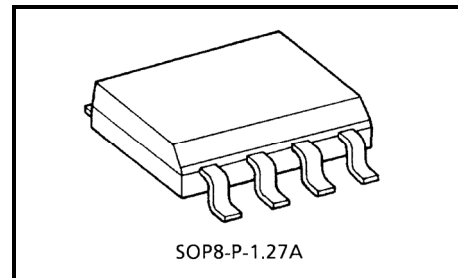
TPD1034F

High-side Power Switch for Motors, Solenoids, and Lamp Drivers

The TPD1034F is a monolithic power IC for high-side switches. The IC has a vertical MOS FET output which can be directly driven from a CMOS or TTL logic circuit (e.g., an MPU). The device offers intelligent self-protection and diagnostic functions.

Features

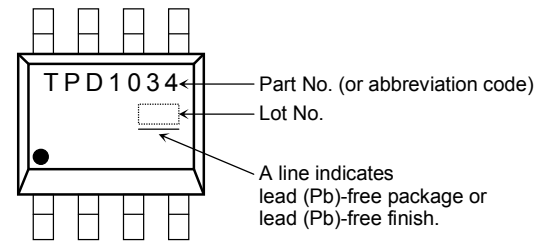
- A monolithic power IC with a new structure combining a control block (Bi-CMOS) and a vertical power MOS FET (IT-MOS) on a single chip.
- One side of the load can be grounded to a high-side switch.
- Can directly drive a power load from a microprocessor.
- Built-in protection against thermal shutdown and load short-circuiting.
- Incorporates a diagnosis function that allows diagnosis output to be read externally at load short-circuiting, opening, or overtemperature
- Up to -10 V of counter electromotive force from an L load can be applied.
- Low on-resistance : $R_{ON} = 80\text{ m}\Omega$ (max)
- Low operating current : $I_{DD} = 1\text{ mA}$ (typ.), (@ $V_{DD} = 12\text{ V}$, $V_{IN} = 0\text{ V}$)
- 8-pin SOP package for surface mounting can be packed in tape.



Weight: 0.08 g (typ.)

Note: Due to its MOS structure, this product is sensitive to static electricity. Handle with care.

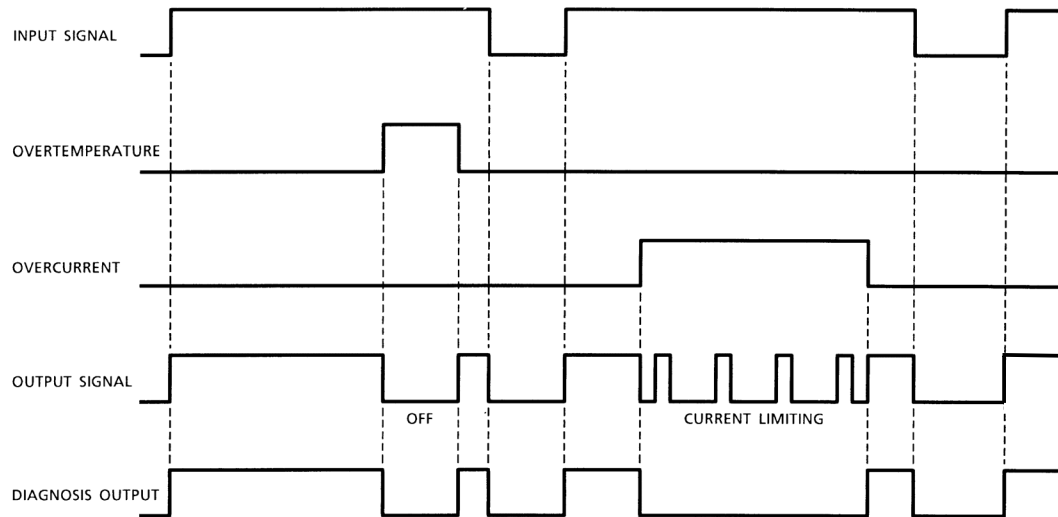
Marking



The block diagram illustrates the internal architecture of the 78L05 voltage regulator. It features a **BANDGAP REFERENCE** block that provides a stable reference voltage to the **REGULATOR** and the **CHARGE PUMP**. The **REGULATOR** block is connected to the **V_{DD}** supply (pin 4) and the **CHARGE PUMP**. The **CHARGE PUMP** is connected to the **DRIVER** block. The **DRIVER** block is connected to the **π-MOS** transistor. The **π-MOS** transistor is connected to the **OUT** pins (pins 5, 6, and 7) and the **CURRENT SENSE** block. The **CURRENT SENSE** block is connected to the **DRIVER** and the **THERMAL SHUTDOWN** block. The **THERMAL SHUTDOWN** block is connected to the **DRIVER** and the **CHARGE PUMP**. The **OVER-VOLTAGE** block is connected to the **V_{DD}** supply and the **CHARGE PUMP**. The **IN** pin (pin 1) is connected to the **CHARGE PUMP** and the **DRIVER**. The **DIAG** pin (pin 2) is connected to the **CHARGE PUMP** and the **DRIVER**. The **GND** pin (pin 3) is connected to the **CHARGE PUMP** and the **DRIVER**.

Pin No.	Symbol	Function
1	IN	Input pin. Input is CMOS-compatible, with pull-down resistor connected. Even if the input is open, output will not accidentally turn on.
2	DIAG	Self-diagnosis detection pin. Goes low when overheating is detected or when output is short-circuited with input on (high). n-channel open drain.
3	GND	Ground pin.
4	V _{DD}	Power pin.
5, 6, 7	OUT	Output pin. When the load is short circuited and current in excess of the detection current (24A typ.) flows to the output pin, the output automatically turns on or off.

Timing Chart



Truth Table

Input Signal	Output Signal	Diagnosis Output	State
H	H	H	Normal
L	L	L	
H	L	L	Overcurrent
L	L	L	
H	H	H	Load open
L	H	H	
H	L	L	Overtemperature
L	L	L	

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DS}	60	V
Supply voltage	DC	$V_{DD(1)}$	25	V
	Pulse	$V_{DD(2)}$	60 ($R_s = 1\Omega$, $\tau = 250\text{ ms}$)	V
Input voltage	DC	$V_{IN(1)}$	-0.5 ~ 12	V
	Pulse	$V_{IN(2)}$	$V_{DD(1)} + 1.5$ ($t = 100\text{ ms}$)	V
Diagnosis output voltage		V_{DIAG}	-0.5 ~ 25	V
Output current		I_O	Internally limited	A
Input current		I_{IN}	± 10	mA
Diagnosis output current		I_{DIAG}	5	mA
Power dissipation (Ta = 25°C)		P_D	1.4 (Note 1)	W
			2.4 (Note 2)	
Operating temperature		T_{opr}	-40 ~ 110	°C
Channel temperature		T_{ch}	150	°C
Storage temperature		T_{stg}	-55 ~ 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Resistance

Characteristic	Symbol	Test Condition	Unit
Thermal resistance	$R_{th(ch-a)}$	89.3 (Note 1)	°C / W
		52.1 (Note 2)	

Note1: Mounted on a glass epoxy board (25.4 mm × 25.4 mm × 0.8 mm) (DC)

Note2: Mounted on a glass epoxy board (25.4 mm × 25.4 mm × 0.8 mm) ($t_w \leq 10\text{ s}$)

Electrical Characteristics

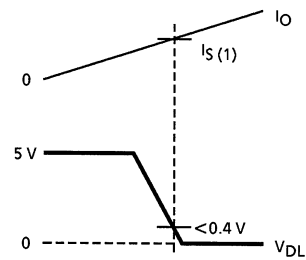
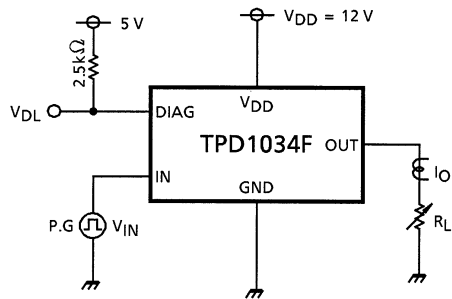
(Unless otherwise specified, $T_{ch} = -40 \sim 110^{\circ}\text{C}$, $V_{DD} = 8 \sim 18\text{ V}$)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Operating supply voltage		$V_{DD}(\text{opr})$	—	—	5	12	18	V
Supply current		I_{DD}	—	$V_{DD} = 12\text{ V}$, $V_{IN} = 0$	—	1	5	mA
Input voltage		V_{IH}	—	$V_{DD} = 12\text{ V}$, $I_O = 8\text{ A}$	3.5	—	—	V
		V_{IL}	—	$V_{DD} = 12\text{ V}$, $I_O = 1.2\text{ mA}$	—	—	1.5	V
Input current		$I_{IN}(1)$	—	$V_{DD} = 12\text{ V}$, $V_{IN} = 5\text{ V}$	—	50	200	μA
		$I_{IN}(2)$	—	$V_{DD} = 12\text{ V}$, $V_{IN} = 0$	-0.2	—	0.2	μA
On-voltage		$V_{DS}(\text{ON})$	—	$V_{DD} = 12\text{ V}$, $I_O = 8\text{ A}$, $T_{ch} = 25^{\circ}\text{C}$	—	—	0.64	V
On-resistance		$R_{DS}(\text{ON})$	—	$V_{DD} = 12\text{ V}$, $I_O = 8\text{ A}$, $T_{ch} = 25^{\circ}\text{C}$	—	—	0.08	Ω
Output leakage current		I_{OL}	—	$V_{DD} = 18\text{ V}$, $V_{IN} = 0$	—	—	1.2	mA
Diagnosis output voltage	"L" Level	V_{DL}	—	$V_{DD} = 12\text{ V}$, $I_{DL} = 2\text{ mA}$	—	—	0.4	V
Diagnosis output current	"H" Level	I_{DH}	—	$V_{DD} = 18\text{ V}$, $V_{DH} = 18\text{ V}$	—	—	10	μA
Overcurrent protection		$I_S(1)$ Note 3	1	$V_{DD} = 12\text{ V}$, $T_{ch} = 25^{\circ}\text{C}$	8	12	—	A
		$I_S(2)$ Note 4	2		15	24	—	A
Thermal shutdown	Temperature	T_S	—	—	150	160	200	$^{\circ}\text{C}$
	Hysteresis	ΔT_S	—		—	10	—	$^{\circ}\text{C}$
Open detection resistance		R_{Ops}	—	$V_{DD} = 8\text{ V}$	1	50	100	k Ω
Switching time		t_{ON}	3	$V_{DD} = 12\text{ V}$, $R_L = 5\Omega$, $T_{ch} = 25^{\circ}\text{C}$	10	200	—	μs
		t_{OFF}	3		10	30	—	μs

Note 3: $I_S(1)$ denotes the overcurrent detection value when the load is short circuited and $V_{IN} = \text{"L"} \rightarrow \text{"H"}$ Note 4: $I_S(2)$ denotes the overcurrent detection value when the load current is increased while $V_{IN} = \text{"H"}$

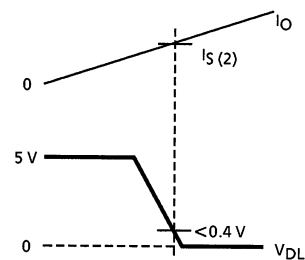
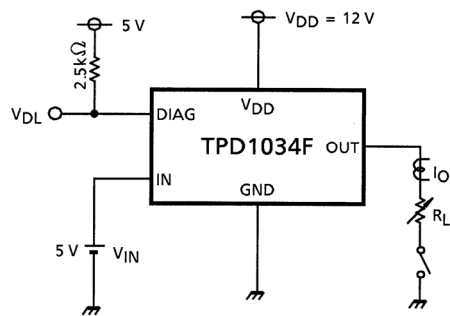
Test Circuit 1

Overcurrent detection



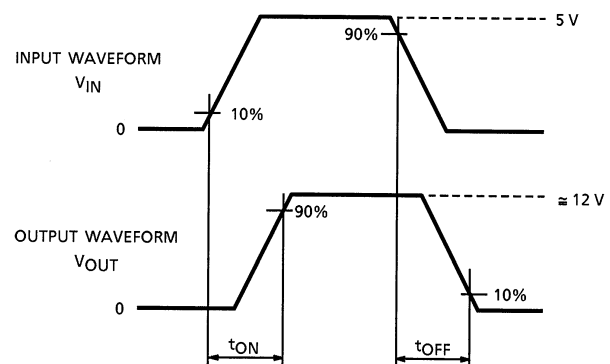
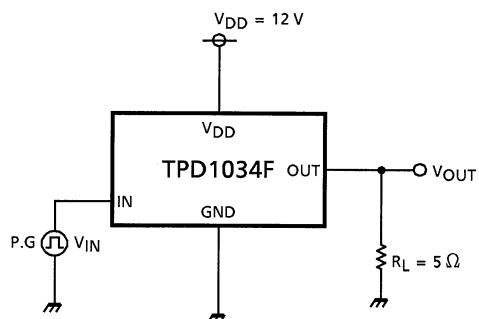
Test Circuit 2

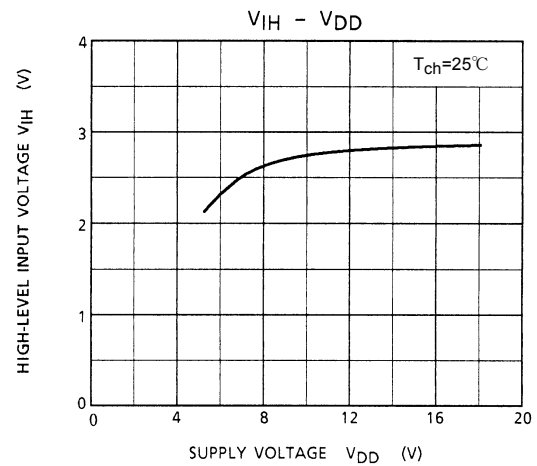
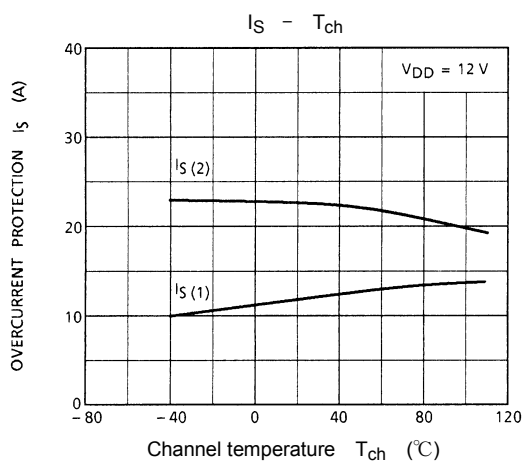
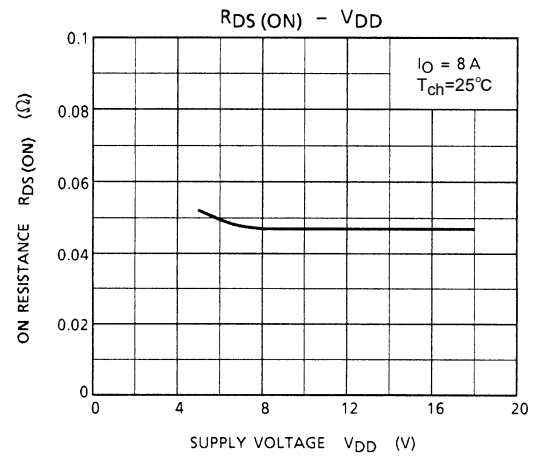
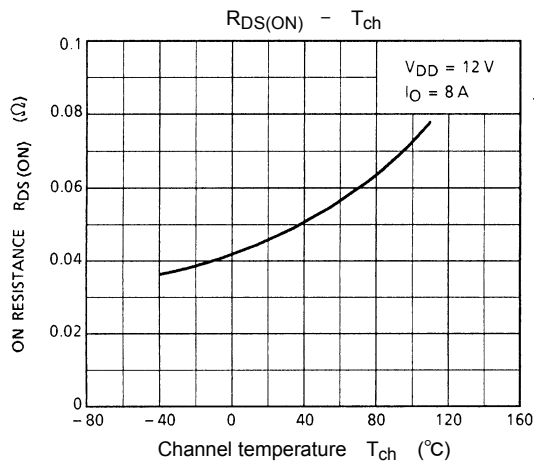
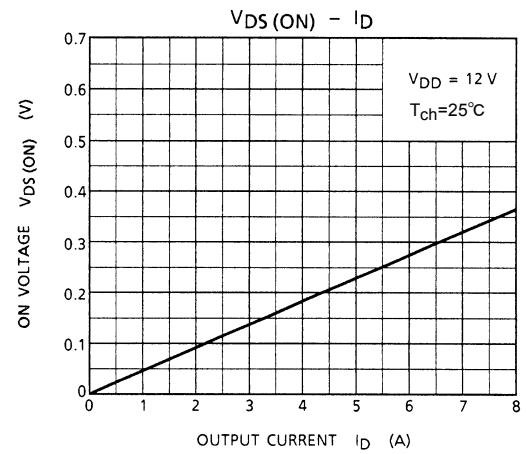
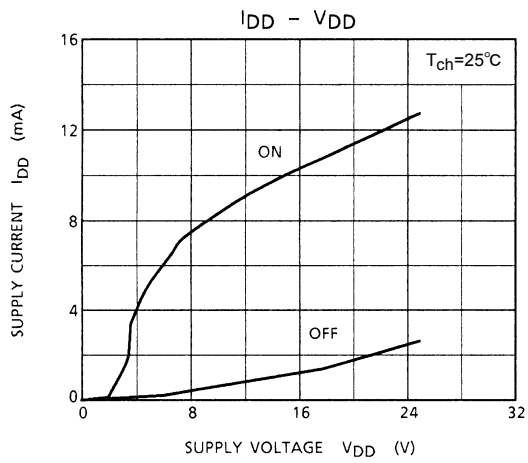
Overcurrent detection

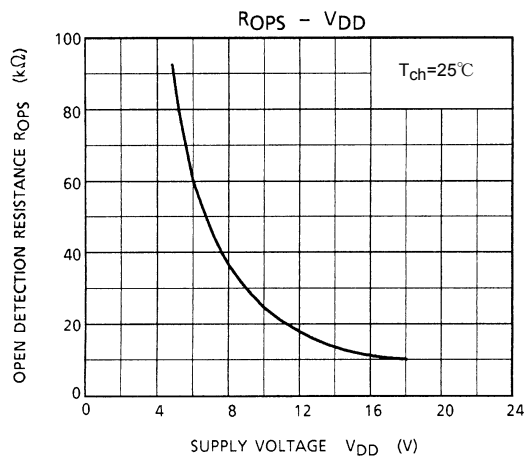
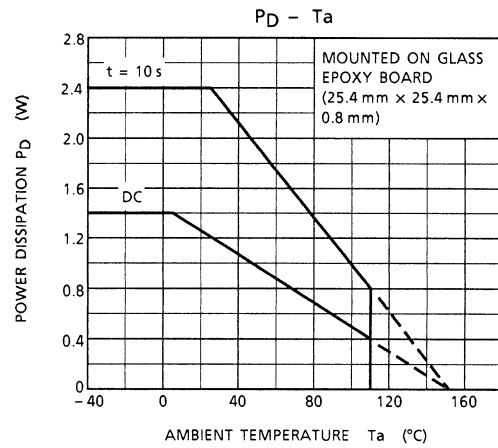
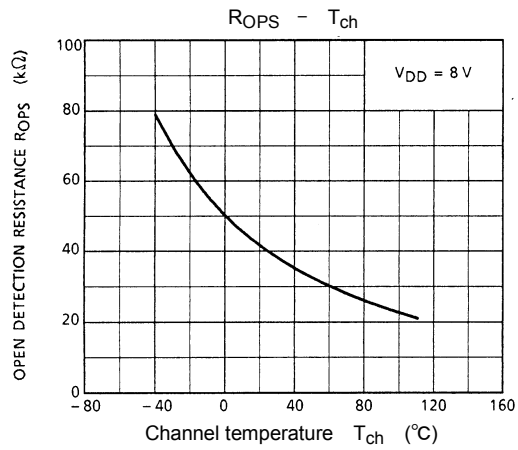
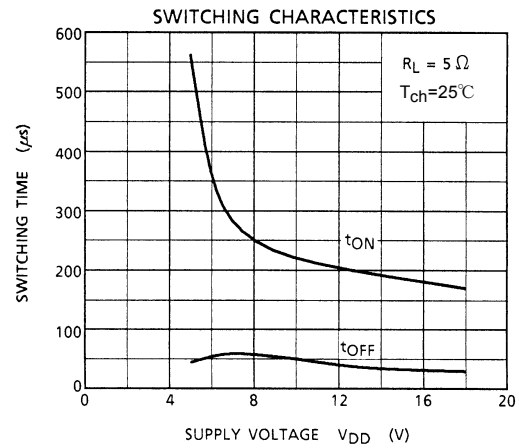
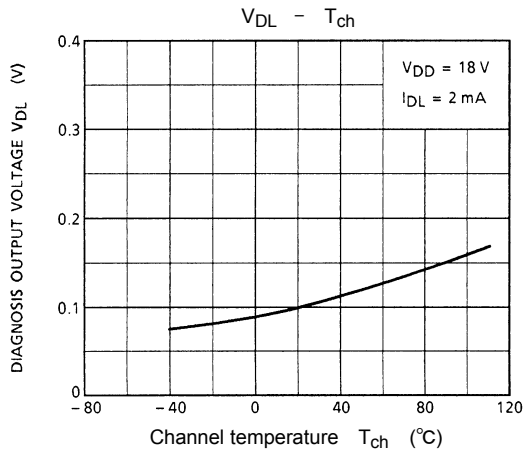


Test Circuit 3

Switching time

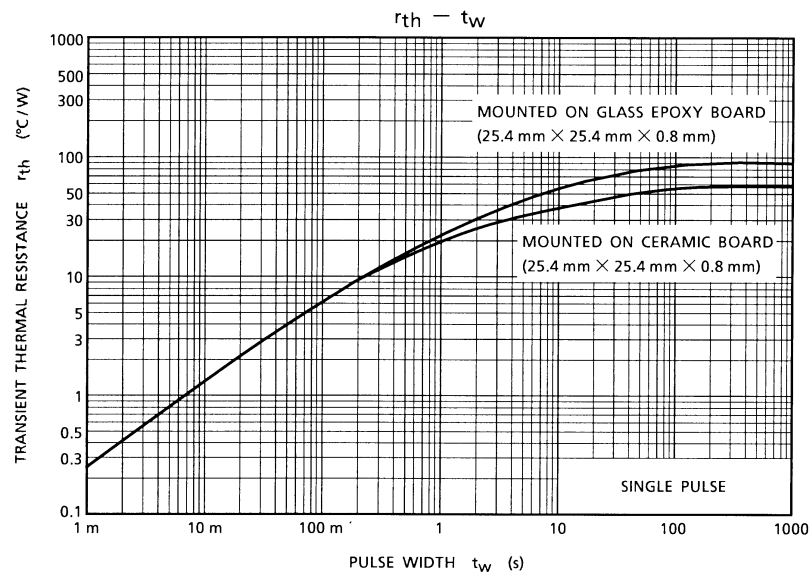






Precaution:

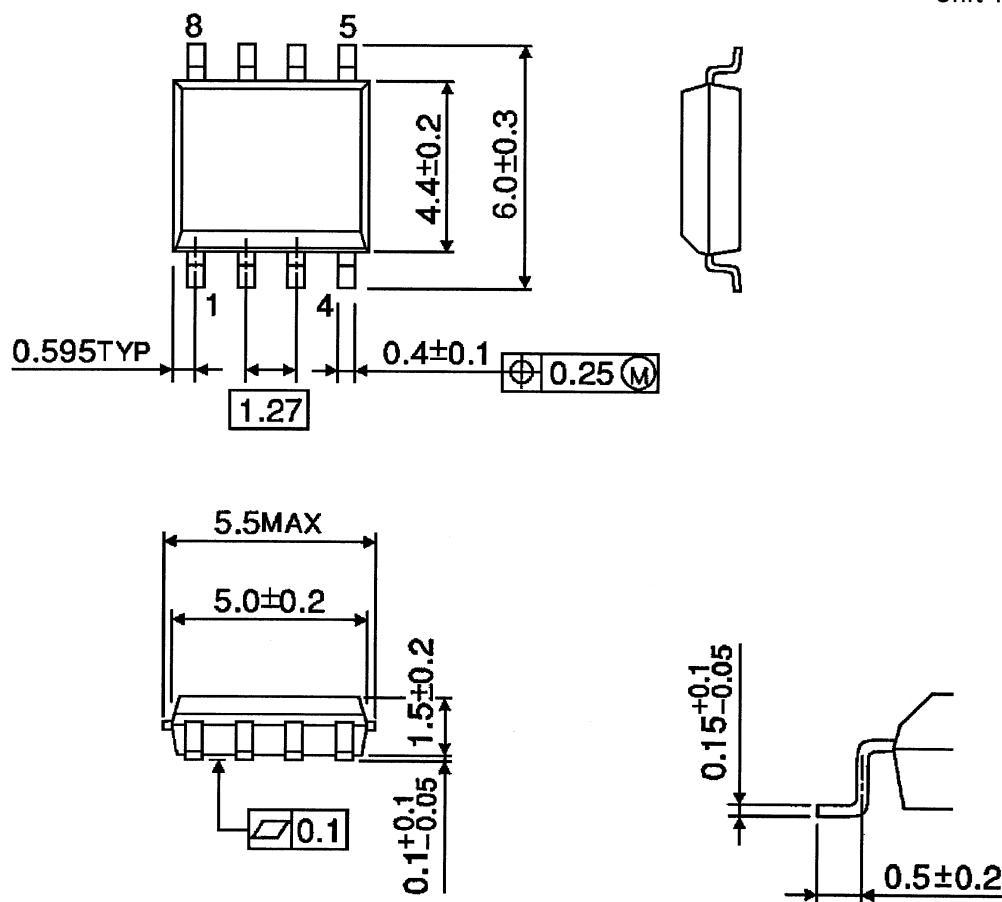
1. Since there is no built-in protection against reverse connection of batteries, etc., provide such protection using external circuits.



Package Dimensions

SOP8-P1.27A

Unit : mm



Weight: 0.08 g (typ.)

RESTRICTIONS ON PRODUCT USE

030619EBA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А